L Number	Hits	Search Text	DB	Time stamp
4	3	(OLED (organic near3 (electro$luminescen$2 EL light$emitting light$emission light$emitter light$emission (light near3 (emission emitting emitter emissive))))) and (penetrat$3 with (charge hole electron) with (luminescen$2 phosphor phosphorescen$3 fluorescen$2))	EPO; JPO; DERWENT	2004/10/15 20:11
5	0	(OLED (organic near3 (electro$luminescen$2 EL light$emitting light$emission light$emitter light$emission (light near3 (emission emitting emitter emissive))))) and (penetrat$3 with (charge hole electron) with (luminescen$2 phosphor phosphorescen$3 fluorescen$2)) and 427/66.ccls.	EPO; JPO; DERWENT	2004/10/15 20:11
6	1	(OLED (organic near3 (electro$luminescen$2 EL light$emitting light$emission light$emitter light$emission (light near3 (emission emitting emitter emissive))))) and (penetrat$3 with (charge hole electron) with (luminescen$2 phosphor phosphorescen$3 fluorescen$2)) and 427/66.ccls.	USPAT; US-PGPUB	2004/10/15 20:12
-	129	((pores porosity porous asperous asperosity rough$6) with (cathode anode electrode)) and 313/500-512.ccls.	USPAT; US-PGPUB	2004/10/14 16:00
-	5	5929561.URPN.	USPAT	2004/03/31 16:51
-	177	((region portion element layer film medium member light) with (EL electro$luminescen$2 emissive emitting emitter emission emits) with (pores porosity porous asperous asperosity rough$6)) and (313/500-512.ccls. 428/690.ccls.)	USPAT; US-PGPUB	2004/03/31 17:16
-	180	((region portion element layer film medium member light) with (EL electro$luminescen$2 emissive emitting ((charge hole) near3 (transfer$3 transport$3)) emitter emission emits) with (pores porosity porous asperous asperosity rough$6)) and (313/500-512.ccls. 428/690.ccls.)	USPAT; US-PGPUB	2004/03/31 17:17
-	181	((region portion element layer film medium member light) with (EL electro$luminescen$2 emissive emitting ((charge electron hole) near3 (transfer$3 transport$3)) emitter emission emits) with (pores porosity porous asperous asperosity rough$6)) and (313/500-512.ccls. 428/690.ccls.)	USPAT; US-PGPUB	2004/03/31 17:29
-	76	(((region portion element layer film medium member light) with (EL electro$luminescen$2 emissive emitting ((charge electron hole) near3 (transfer$3 transport$3)) emitter emission emits) with (pores porosity porous asperous asperosity rough$6)) and (313/500-512.ccls. 428/690.ccls.)) not @ad>20001005	USPAT; US-PGPUB	2004/03/31 17:18
-	3	("3819973" | "5469020" | "5485355").PN.	USPAT	2004/03/31 17:24
-	7	5869930.URPN.	USPAT	2004/03/31 17:24
-	2437	((region portion element layer film medium member light) with (EL electro$luminescen$2 emissive emitting ((charge electron hole) near3 (transfer$3 transport$3)) emitter emission emits) with (pores porosity porous asperous asperosity rough$6))	EPO; JPO; DERWENT	2004/03/31 17:29
-	1033	((region portion element layer film medium member light) with (EL electro$luminescen$2 emissive emitting ((charge electron hole) near3 (transfer$3 transport$3)) emitter emission emits) with (pores porosity porous asperous asperosity rough$6)) and (display device panel)	EPO; JPO; DERWENT	2004/03/31 17:30
-	828	(((region portion element layer film medium member light) near4 (EL electro$luminescen$2 emissive emitting ((charge electron hole) near3 (transfer$3 transport$3)) emitter emission emits)) with (pores porosity porous asperous asperosity rough$6)) and (display device panel)	EPO; JPO; DERWENT	2004/03/31 17:31
-	341	(((region portion element layer film medium member light) near4 (EL electro$luminescen$2 emissive emitting ((charge electron hole) near3 (transfer$3 transport$3)) emitter emission emits)) with (pores porosity porous asperous asperosity rough$6)) and ((display device panel) near3 (EL electro$luminescen$2 OLED (light near3 (emitting emitter emission emissive))))	EPO; JPO; DERWENT	2004/03/31 17:37

-	171	(((region portion element layer film medium member light) near4 (EL electro$luminescen$2 emissive emitting ((charge electron hole) near3 (transfer$3 transport$3)) emitter emission emits)) with (surface superficie) with (pores porosity porous asperous asperosity rough$6)) and ((display device panel) near3 (EL electro$luminescen$2 OLED (light near3 (emitting emitter emission emissive))))	EPO; JPO; DERWENT	2004/03/31 17:59
-	1	1995-218659.NRAN.	DERWENT	2004/03/31 17:44
-	1	1999-410108.NRAN.	DERWENT	2004/03/31 17:51
-	356	(((region portion element layer film medium member light) near4 (EL electro$luminescen$2 emissive emitting ((charge electron hole) near3 (transfer$3 transport$3)) emitter emission emits)) with (surface superficie) with (pores porosity porous asperous asperosity rough$6)) and ((display device panel) near3 (EL electro$luminescen$2 OLED (light near3 (emitting emitter emission emissive))))	USPAT; US-PGPUB	2004/03/31 18:00
-	7218	(((region portion element layer film medium member light) near4 (EL electro$luminescen$2 emissive emitting ((charge electron hole) near3 (transfer$3 transport$3)) emitter emission emits)) with (distribution concentration amount)) and ((display device panel) near3 (EL electro$luminescen$2 OLED (light near3 (emitting emitter emission emissive))))	USPAT; US-PGPUB	2004/03/31 18:02
-	1084	(((region portion element layer film medium member light) near4 (EL electro$luminescen$2 emissive emitting ((charge electron hole) near3 (transfer$3 transport$3)) emitter emission emits)) with (distribution concentration amount)) and (313/500-512.ccls. 428/690.ccls.)	USPAT; US-PGPUB	2004/03/31 18:02
-	642	(((region portion element layer film medium member light) with (EL electro$luminescen$2 emissive emitting ((charge electron hole) near3 (transfer$3 transport$3)) emitter emission emits)) with (distribution concentration)) and (313/500-512.ccls. 428/690.ccls.)	USPAT; US-PGPUB	2004/03/31 18:03
-	469	(((region portion element layer film medium member light) with (EL electro$luminescen$2 emissive emitting ((charge electron hole) near3 (transfer$3 transport$3)) emitter emission emits)) with concentration) and (313/500-512.ccls. 428/690.ccls.)	USPAT; US-PGPUB	2004/03/31 18:03
-	469	(((region portion element layer film medium member light) with (EL electro$luminescen$2 emissive emitting ((charge electron hole) near3 (transfer$3 transport$3)) emitter emission emits)) with concentration) and (313/500-512.ccls. 428/690.ccls.)	USPAT; US-PGPUB	2004/04/01 11:27
-	380	(((region portion element layer film medium member light) with (EL electro$luminescen$2 emissive emitting ((charge electron hole) near3 (transfer$3 transport$3)) emitter emission emits)) with concentration) and (313/502-504.ccls. 428/690.ccls.)	USPAT; US-PGPUB	2004/04/01 11:28
-	335	(((region portion element layer film medium member light) with (EL electro$luminescen$2 emissive emitting ((charge electron hole) near3 (transfer$3 transport$3)) emitter emission emits)) with concentration) and organic and (313/502-504.ccls. 428/690.ccls.)	USPAT; US-PGPUB	2004/04/01 15:45
-	8	"04357694" "11074083" "07235378" "08279628"	EPO; JPO; DERWENT	2004/04/01 11:29
-	20	(((region portion element layer film medium member light) with (EL electro$luminescen$2 emissive emitting ((charge electron hole) near3 (transfer$3 transport$3)) emitter emission emits)) with concentration with gradient) and organic and (313/502-504.ccls. 428/690.ccls.)	USPAT; US-PGPUB	2004/04/01 15:47
-	27	(((region portion element layer film medium member light) with (EL electro$luminescen$2 emissive emitting ((charge electron hole) near3 (transfer$3 transport$3)) emitter emission emits)) with concentration with gradient) and (313/500-512.ccls. 428/690.ccls.)	USPAT; US-PGPUB	2004/04/01 16:47

-	97	(((region portion element layer film medium member light) with (EL luminescen$3 electro$luminescen$2 emissive emitting ((charge electron hole) near3 (transfer$3 transport$3)) emitter emission emits)) with concentration with gradient)	EPO; JPO; DERWENT	2004/04/01 16:48
-	223	(((region portion element layer film medium member light) with (EL luminescen$3 electro$luminescen$2 emissive emitting ((charge electron hole) near3 (transfer$3 transport$3)) emitter emission emits)) with concentration with gradient)	USPAT; US-PGPUB	2004/04/01 17:16
-	67	((region portion element layer film member medium matrix) with (EL electro$luminescen$2 emission emitting emissive emit emitter organic ((hole charge electron) near3 (transport$3 transfer$3))) with concentration with (graded gradient grading rate distribution)) and (313/500-512.ccls. 428/690.ccls.)	USPAT; US-PGPUB	2004/04/01 17:31
-	40	(((region portion element layer film member medium matrix) with (EL electro$luminescen$2 emission emitting emissive emit emitter organic ((hole charge electron) near3 (transport$3 transfer$3))) with concentration with (graded gradient grading rate distribution)) and (313/500-512.ccls. 428/690.ccls.)) not @ad>20001005	USPAT; US-PGPUB	2004/04/01 17:31
-	47	((region portion element layer film member medium matrix) with (EL electro$luminescen$2 emission emitting emissive emit emitter organic ((hole charge electron) near3 (transport$3 transfer$3))) with concentration with (variation varying vary varies change changing)) and (313/500-512.ccls. 428/690.ccls.)	USPAT; US-PGPUB	2004/04/01 17:35
-	30	(((region portion element layer film member medium matrix) with (EL electro$luminescen$2 emission emitting emissive emit emitter organic ((hole charge electron) near3 (transport$3 transfer$3))) with concentration with (variation varying vary varies change changing)) and (313/500-512.ccls. 428/690.ccls.)) not @ad>20001005	USPAT; US-PGPUB	2004/04/01 18:03
-	613	((region portion element layer film member medium matrix) with (EL electro$luminescen$2 emission emitting emissive emit emitter organic ((hole charge electron) near3 (transport$3 transfer$3))) with concentration with (graded gradient grading rate distribution variation varying vary varies change changing))	EPO; JPO; DERWENT	2004/04/01 17:35
-	231	((region portion element layer film member medium matrix) with (EL electro$luminescen$2 emission emitting emissive emit emitter organic ((hole charge electron) near3 (transport$3 transfer$3))) with concentration with (graded gradient grading rate distribution variation varying vary varies change changing)) and (display device panel)	EPO; JPO; DERWENT	2004/04/01 17:38
-	48	((region portion element layer film member medium matrix) with (EL electro$luminescen$2 emission emitting emissive emit emitter organic ((hole charge electron) near3 (transport$3 transfer$3))) with concentration with (graded gradient grading rate distribution variation varying vary varies change changing)) and (display device panel) and (electrode cathode anode)	EPO; JPO; DERWENT	2004/04/01 17:45
-	1	2004-076874.NRAN.	DERWENT	2004/04/01 17:44
-	134	((region portion element layer film member medium matrix) same (EL electro$luminescen$2 emission emitting emissive emit emitter organic ((hole charge electron) near3 (transport$3 transfer$3))) same concentration same (graded gradient grading rate distribution variation varying vary varies change changing)) and (display device panel) and (electrode cathode anode)	EPO; JPO; DERWENT	2004/04/01 17:46
-	138	((region portion element layer material dopant doping doped film member medium matrix) same (EL electro$luminescen$2 emission emitting emissive emit emitter organic ((hole charge electron) near3 (transport$3 transfer$3))) same concentration same (graded gradient grading rate distribution variation varying vary varies change changing)) and (display device panel) and (electrode cathode anode)	EPO; JPO; DERWENT	2004/04/01 18:01

-		90	(((region portion element layer material dopant doping doped film member medium matrix) same (EL electro$luminescen$2 emission emitting emissive emit emitter organic ((hole charge electron) near3 (transport$3 transfer$3))) same concentration same (graded gradient grading rate distribution variation varying vary varies change changing)) and (display device panel) and (electrode cathode anode)) not (((region portion element layer film member medium matrix) with (EL electro$luminescen$2 emission emitting emissive emit emitter organic ((hole charge electron) near3 (transport$3 transfer$3))) with concentration with (graded gradient grading rate distribution variation varying vary varies change changing)) and (display device panel) and (electrode cathode anode))	EPO; JPO; DERWENT	2004/04/01 17:47
-		282	((region portion element layer material dopant doping doped film member medium matrix) same (EL active electro$luminescen$2 emission emitting emissive emit emitter organic ((hole charge electron) near3 (transport$3 transfer$3))) same concentration same (graded gradient grading rate distribution variation varying vary varies change changing)) and (display device panel) and (electrode cathode anode) and (313/500-512.ccls. 428/690.ccls.)	USPAT; US-PGPUB	2004/04/01 18:02
-		165	(((region portion element layer material dopant doping doped film member medium matrix) same (EL active electro$luminescen$2 emission emitting emissive emit emitter organic ((hole charge electron) near3 (transport$3 transfer$3))) same concentration same (graded gradient grading rate distribution variation varying vary varies change changing)) and (display device panel) and (electrode cathode anode) and (313/500-512.ccls. 428/690.ccls.)) not @ad>20001005	USPAT; US-PGPUB	2004/04/02 11:43
-		7	("5429884" | "5739635" | "5773929" | "5776622" | "5776623" | "5909081" | "5920080").PN.	USPAT	2004/04/02 11:17
- ·		8	6064151.URPN.	USPAT	2004/04/02 11:18
-		56	((graded gradient grading distribution variation varying vary varies change changing) with ((charge hole electron) near3 (transport$3 transfer$3)) with (diffus$3 concentration amount dopant doping doped)) and (313/500-512.ccls. 428/690.ccls.) and (electrode anode cathode)	USPAT; US-PGPUB	2004/04/02 12:45
-		57	((graded gradient grading distribution variation varying vary varies change changing) with ((charge hole electron) near3 (transport$3 transfer$3)) with (diffus$3 concentration amount dopant doping doped)) and (electrode anode cathode)	EPO; JPO; DERWENT	2004/04/02 12:49
-		175	((graded gradient grading distribution variation density varying vary varies change changing) same ((charge hole electron) near3 (transport$3 transfer$3)) same (diffus$3 concentration amount dopant doping doped)) and (electrode anode cathode)	EPO; JPO; DERWENT	2004/04/02 12:50
-		118	(((graded gradient grading distribution variation density varying vary varies change changing) same ((charge hole electron) near3 (transport$3 transfer$3)) same (diffus$3 concentration amount dopant doping doped)) and (electrode anode cathode)) not (((graded gradient grading distribution variation varying vary varies change changing) with ((charge hole electron) near3 (transport$3 transfer$3)) with (diffus$3 concentration amount dopant doping doped)) and (electrode anode cathode))	EPO; JPO; DERWENT	2004/04/02 12:50
-		94	(((charge hole electron) near3 (transfer$3 transport$3)) near3 (material dopant doped doping medium particle material)) same ((luminescen$3 emitter emission emissive emitting) near3 (dopant doped doping medium particle material)) same (matrix medium)) and 428/690.ccls.	USPAT; US-PGPUB	2004/04/02 14:30
-		87	(((charge hole) near3 (transfer$3 transport$3) near3 (material dopant doped doping medium particle material)) same ((luminescen$3 emitter emission emissive emitting) near3 (dopant doped doping medium particle material)) same (matrix medium)) and 428/690.ccls.	USPAT; US-PGPUB	2004/04/02 14:33

-		97	(((charge hole) near3 (transfer$3 transport$3) near3 (material dopant doped doping medium particle material)) same ((luminescen$3 emitter emission emissive emitting) near3 (dopant doped doping medium particle material)) same (matrix medium)) and 313/503-504.ccls.	USPAT; US-PGPUB	2004/04/02 14:47
-		10	(((charge hole) near3 (transfer$3 transport$3) near3 (diffus$3 dopant doped doping)) same ((luminescen$3 emitter emission emissive emitting) near3 (diffus$3 dopant doped doping)) same (matrix medium)) and 313/503-504.ccls.	USPAT; US-PGPUB	2004/04/02 14:49
-		14	(((charge hole) near5 (transfer$3 transport$3) near3 (diffus$3 dopant doped doping)) same ((luminescen$3 emitter emission emissive emitting) near5 (diffus$3 dopant doped doping)) same (matrix medium)) and 428/690.ccls.	USPAT; US-PGPUB	2004/04/02 14:50
-		0	(((charge hole) near5 (transfer$3 transport$3) near3 (diffus$3 dopant doped penetrat$3 doping)) same ((luminescen$3 emitter emission emissive emitting) near5 (diffus$3 dopant penetrat$3 doped doping)) same (matrix medium))	EPO; JPO; DERWENT	2004/04/02 14:50
-		5	(((charge hole) near5 (transfer$3 transport$3) near3 (diffus$3 dopant doped penetrat$3 doping)) same ((luminescen$3 emitter emission emissive emitting) near5 (diffus$3 dopant penetrat$3 doped doping)) same (matrix host medium))	EPO; JPO; DERWENT	2004/04/02 14:52
-		8	(((charge electron hole) near5 (transfer$3 transport$3) near3 (diffus$3 dopant doped penetrat$3 doping)) same ((luminescen$3 emitter emission emissive emitting) near5 (diffus$3 dopant penetrat$3 doped doping)) same (matrix host medium))	EPO; JPO; DERWENT	2004/04/02 14:53
-		9	(((charge electron hole) with (transfer$3 transport$3) near3 (diffus$3 dopant doped penetrat$3 doping)) same ((luminescen$3 emitter emission emissive emitting) with (diffus$3 dopant penetrat$3 doped doping)) same (matrix host medium))	EPO; JPO; DERWENT	2004/04/02 14:54
-		54	((((charge electron hole) with (transfer$3 transport$3) near3 (diffus$3 dopant doped penetrat$3 doping)) same ((luminescen$3 emitter emission emissive emitting) with (diffus$3 dopant penetrat$3 doped doping)) same (matrix host medium))) and 313/502-504.ccls.	USPAT; US-PGPUB	2004/04/02 14:58
-		48	((((charge electron hole) with (transfer$3 transport$3) near3 (diffus$3 dopant doped penetrat$3 doping)) same ((luminescen$3 emitter emission emissive emitting) with (diffus$3 dopant penetrat$3 doped doping)) same (matrix host medium))) and 428/690.ccls.	USPAT; US-PGPUB	2004/04/02 14:59
-		199	(((charge electron hole) with (transfer$3 transport$3) with (diffus$3 dopant doped penetrat$3 doping)) same ((luminescen$3 emitter emission emissive emitting) with (diffus$3 dopant penetrat$3 doped doping)) same ((emission emitting emissive emitter active) near3 (film layer region member portion element))) and 428/690.ccls.	USPAT; US-PGPUB	2004/04/02 15:02
-		258	(((charge electron hole) with (transfer$3 transport$3) with (diffus$3 dopant doped penetrat$3 doping)) same ((luminescen$3 emitter emission emissive emitting) with (diffus$3 dopant penetrat$3 doped doping)) same ((emission emitting emissive emitter active) near3 (film layer region member portion element))) and 313/502-504.ccls.	USPAT; US-PGPUB	2004/04/02 15:02
-		96	(((charge electron hole) near3 (transfer$3 transport$3) near5 (diffus$3 dopant doped penetrat$3 doping)) same ((luminescen$3 emitter emission emissive emitting) near5 (diffus$3 dopant penetrat$3 doped doping)) same ((emission emitting emissive emitter active) near3 (film layer region member portion element))) and 428/690.ccls.	USPAT; US-PGPUB	2004/04/02 15:06
-		135	(((charge electron hole) near3 (transfer$3 transport$3) near5 (diffus$3 dopant doped penetrat$3 doping)) same ((luminescen$3 emitter emission emissive emitting) near5 (diffus$3 dopant penetrat$3 doped doping)) same ((emission emitting emissive emitter active) near3 (film layer region member portion element))) and 313/500-512.ccls.	USPAT; US-PGPUB	2004/04/02 15:08

-	268	(((charge electron hole) near3 (transfer$3 transport$3) near5 (diffus$3 dopant doped penetrat$3 doping)) same ((luminescen$3 phosphor fluorescen$3 phosphorescen$3 photo$luminescen$3 luminophor fluorophor emitter emission emissive emitting) near5 (diffus$3 dopant penetrat$3 doped doping)) same (((emission emitting emissive emitter active) near3 (film layer region member portion element)) medium matrix host))	USPAT; US-PGPUB	2004/04/02 15:11
-	25	(((charge electron hole) near3 (transfer$3 transport$3) near5 (diffus$3 dopant doped penetrat$3 doping)) same ((luminescen$3 phosphor fluorescen$3 phosphorescen$3 photo$luminescen$3 luminophor fluorophor emitter emission emissive emitting) near5 (diffus$3 dopant penetrat$3 doped doping)) same (((emission emitting emissive emitter active) near3 (film layer region member portion element)) medium matrix host))	EPO; JPO; DERWENT	2004/04/02 15:27
-	0	6066357.ccls.	USPAT; US-PGPUB	2004/04/02 15:28
-	1	6066357.pn.	USPAT; US-PGPUB	2004/04/02 18:10
-	6	("4356429" | "4539507" | "4720432" | "4769292" | "5294869" | "5294870").PN.	USPAT	2004/04/02 15:29
-	4	6066357.URPN.	USPAT	2004/04/02 15:29
-	2	"04357694"	EPO; JPO; DERWENT	2004/04/02 18:10
-	1	1993-031086.NRAN.	DERWENT	2004/04/02 18:10
-	4	("5151629" | "5755999" | "5804322" | "5834130").PN.	USPAT	2004/04/03 09:27
-	9	5925980.URPN.	USPAT	2004/04/03 09:27
-	24	choong-v$.in.	EPO; JPO; DERWENT	2004/04/03 09:59
-	6	((electron near3 (transfer$3 transport$3)) with (rough$5 porous porosity pores)) and 313/500-512.ccls.	USPAT; US-PGPUB	2004/04/03 10:02
-	3	((electron near3 (transfer$3 transport$3)) with (rough$5 porous porosity pores)) and 428/690.ccls.	USPAT; US-PGPUB	2004/04/03 10:03
-	41	((electron near3 (transfer$3 transport$3)) with (rough$5 porous porosity pores))	EPO; JPO; DERWENT	2004/04/03 10:06
-	0	((electron near3 (transfer$3 transport$3)) with (rough$5 porous porosity pores)) and 427/$.ccls.	EPO; JPO; DERWENT	2004/04/03 10:07
-	15	((electron near3 (transfer$3 transport$3)) with (rough$5 porous porosity pores)) and 427/$.ccls.	USPAT; US-PGPUB	2004/04/03 10:08
-	14	((electron near3 (transfer$3 transport$3)) with (rough$5 porous porosity pores)) and 428/$.ccls.	USPAT; US-PGPUB	2004/04/03 10:09
-	3	((electron near3 (transfer$3 transport$3)) with (rough$5 porous porosity pores)) and 445/$.ccls.	USPAT; US-PGPUB	2004/04/03 10:09
-	13	((electron near3 (transfer$3 transport$3)) with (rough$5 porous porosity pores)) and 313/$.ccls.	USPAT; US-PGPUB	2004/04/03 10:11
-	9	((electron near3 (transfer$3 transport$3)) with (rough$5 porous porosity pores)) and 438/$.ccls.	USPAT; US-PGPUB	2004/04/03 10:11
-	31	((electron near3 (transfer$3 transport$3)) with (rough$5 porous porosity pores)) and 257/$.ccls.	USPAT; US-PGPUB	2004/04/03 10:15
-	72	313/500-512.ccls. and ((porous porosity rough$5 pores) same (solvent etch$3))	USPAT; US-PGPUB	2004/04/03 10:27
-	9	313/500-512.ccls. and ((porous porosity rough$5 pores) same silicon same (solvent etch$3))	USPAT; US-PGPUB	2004/04/03 10:27
-	402	427/$.ccls. and ((porous porosity rough$5 pores) same silicon same (solvent etch$3))	USPAT; US-PGPUB	2004/04/03 10:27
-	2185	438/$.ccls. and ((porous porosity rough$5 pores) same silicon same (solvent etch$3))	USPAT; US-PGPUB	2004/04/03 10:28
-	871	438/$.ccls. and ((porous porosity rough$5 pores) with silicon with (solvent etch$3))	USPAT; US-PGPUB	2004/04/03 10:28
-	99	427/$.ccls. and ((porous porosity rough$5 pores) with silicon with (solvent etch$3))	USPAT; US-PGPUB	2004/04/03 10:29
-	23	313/$.ccls. and ((porous porosity rough$5 pores) with silicon with (solvent etch$3))	USPAT; US-PGPUB	2004/04/03 10:31
-	1	313/$.ccls. and ((porous porosity rough$5 pores) with silicon with (wet$etch$3 (wet near3 etch$3)))	USPAT; US-PGPUB	2004/04/03 10:32

-	7	428/$.ccls. and ((porous porosity rough$5 pores) with silicon with (wet$etch$3 (wet near3 etch$3)))	USPAT; US-PGPUB	2004/04/03 10:32
-	338	(((electron hole charge) near3 (transport$3 transfer$4)) with (medium matrix)) and (313/504,503.ccls. 428/690.ccls.)	USPAT; US-PGPUB	2004/10/13 20:02
-	19	(OLED (organic near3 (electro$luminescen$2 EL light$emitting light$emission light$emitter light$emission (light near3 (emission emitting emitter emissive))))) and steam$3	EPO; JPO; DERWENT	2004/10/14 19:13
-	1	2000-463420.NRAN.	DERWENT	2004/10/13 20:24
-	63	(313/$.ccls. 427/$.ccls. 428/$.ccls. 438/$.ccls. 445/$.ccls.) and (OLED (organic near3 (electro$luminescen$2 EL light$emitting light$emission light$emitter light$emission (light near3 (emission emitting emitter emissive))))) and steam$3	USPAT; US-PGPUB	2004/10/13 20:37
-	1	5895692.pn.	USPAT; US-PGPUB	2004/10/14 16:02
-	60	(OLED (organic near3 (electro$luminescen$2 EL light$emitting light$emission light$emitter light$emission (light near3 (emission emitting emitter emissive))))) and ((steam$3 evaporat$3 (vapor near3 deposit$3)) with (luminescen$2 phosphor fluorescen$2)) and 427/66.ccls.	USPAT; US-PGPUB	2004/10/15 20:08
-	5	(OLED (organic near3 (electro$luminescen$2 EL light$emitting light$emission light$emitter light$emission (light near3 (emission emitting emitter emissive))))) and ((steam$3 evaporat$3 (vapor near3 deposit$3)) same (ink$jet$4 (ink near3 jet$4)) same (luminescen$2 phosphor fluorescen$2)) and 427/66.ccls.	USPAT; US-PGPUB	2004/10/14 19:32
-	31	(OLED (organic near3 (electro$luminescen$2 EL light$emitting light$emission light$emitter light$emission (light near3 (emission emitting emitter emissive))))) and ((steam$3 evaporat$3 (vapor near3 deposit$3)) same (luminescen$2 phosphor fluorescen$2)) and (ink$jet$4 (ink near3 jet$4)) and 427/66.ccls.	USPAT; US-PGPUB	2004/10/14 19:33
-	6	6066357.URPN.	USPAT	2004/10/14 20:38
-	6	6066357.URPN.	USPAT	2004/10/14 20:39
-	6	("4356429" | "4539507" | "4720432" | "4769292" | "5294869" | "5294870").PN.	USPAT	2004/10/14 20:39
-	222	(OLED (organic near3 (electro$luminescen$2 EL light$emitting light$emission light$emitter light$emission (light near3 (emission emitting emitter emissive))))) and ((porous porosity pores permeable permeability) with (cathode anode electrode))	USPAT; US-PGPUB	2004/10/14 20:49
-	91	(OLED (organic near3 (electro$luminescen$2 EL light$emitting light$emission light$emitter light$emission (light near3 (emission emitting emitter emissive))))) and ((porous porosity pores permeable permeability) with (surface superficie area region side boundary interface) with (cathode anode electrode))	USPAT; US-PGPUB	2004/10/14 20:58
-	2906	(OLED (organic near3 (electro$luminescen$2 medium element film layer EL light$emitting light$emission light$emitter light$emission (light near3 (emission emitting emitter emissive)))) same ((porous porosity pores permeable permeability) with (surface superficie area region side boundary interface))) and (electrode cathode anode)	USPAT; US-PGPUB	2004/10/14 21:00
-	615	(OLED (organic near3 (electro$luminescen$2 medium element film layer EL light$emitting light$emission light$emitter light$emission (light near3 (emission emitting emitter emissive)))) same ((porous porosity pores permeable permeability) with (surface superficie area region side boundary interface))) and (electrode cathode anode)	EPO; JPO; DERWENT	2004/10/14 21:00
-	2737	(OLED (organic near3 (electro$luminescen$2 medium element film layer EL light$emitting light$emission light$emitter light$emission (light near3 (emission emitting emitter emissive)))) with ((porous porosity pores permeable permeability) with (surface superficie area region side boundary interface))) and (electrode cathode anode)	USPAT; US-PGPUB	2004/10/14 21:00

-		583	(OLED (organic near3 (electro$luminescen$2 luminescen$3 fluorescen$2 medium element film layer EL light$emitting light$emission light$emitter light$emission (light near3 (emission emitting emitter emissive)))) with ((porous porosity pores permeable permeability) with (surface superficie area region side boundary interface))) and (electrode cathode anode)	EPO; JPO; DERWENT	2004/10/14 21:02
-		485	(OLED (organic near3 (electro$luminescen$2 luminescen$3 fluorescen$2 medium element film layer EL light$emitting light$emission light$emitter light$emission (light near3 (emission emitting emitter emissive)))) with ((porous porosity pores permeable permeability) with (surface superficie area region side boundary interface))) and (electrode cathode anode) and (device display panel)	EPO; JPO; DERWENT	2004/10/14 21:03
-		14	((OLED (organic near3 (electro$luminescen$2 material luminescen$3 fluorescen$2 medium element film layer EL light$emitting light$emission light$emitter light$emission (light near3 (emission emitting emitter emissive))))) with (porous porosity pores permeable permeability) with (surface superficie area region side boundary interface)) and (electrode cathode anode) and ((OLED (organic near3 (electro$luminescen$2 EL light$emitting light$emission light$emitter light$emission (light near3 (emission emitting emitter emissive))))) with (device display panel))	EPO; JPO; DERWENT	2004/10/14 21:11
-		53	((OLED (organic near3 (electro$luminescen$2 material luminescen$3 fluorescen$2 medium element film layer EL light$emitting light$emission light$emitter light$emission (light near3 (emission emitting emitter emissive))))) with (porous porosity pores permeable permeability) with (surface superficie area region side boundary interface)) and (electrode cathode anode) and ((OLED (organic near3 (electro$luminescen$2 EL light$emitting light$emission light$emitter light$emission (light near3 (emission emitting emitter emissive))))) with (device display panel))	USPAT; US-PGPUB	2004/10/14 21:11